

### 1-Line Bi-directional ESD Protection Diode

#### **Description**

These surge protection diodes are designed for applications requiring transient over voltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

#### **Features**

- Bi-directional ESD protection of one line
- Reverse stand-off voltage: 24.0V Max
- Low leakage current: nA Level
- Response time is typically < 1 ns</li>
- Complies with following standards:

—IEC 61000-4-2 (ESD) immunity test

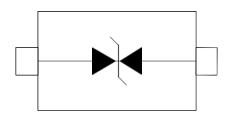
Air discharge: ±20kV

Contact discharge: ±15kV

-IEC61000-4-5 (Lightning) 6.0A (8/20µs)

RoHS Compliant

### **Schematic and Pin Configuration**



SOD-323 (Top View)
Circuit Schematic

#### **Mechanical Characteristics**

- SOD-323 Small Outline Plastic Package
- Level 1 moisture sensitivity per J-STD-020
- Case Material: "Green" Molding Compound
- Lead Finish: Matte Tin
- We declare that the material of product compliance With RoHS requirements and Halogen Free

### **Applications**

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA'S)
- Notebooks, Desktops, and Servers

### **Marking Information**



24B = Device Marking Code

### **Ordering Information**

Part Number	Shipping	Reel Size
PSD24C	3000/Tape &Reel	7 inch



# Absolute Maximum Ratings (TA=25°C unless otherwise specified)

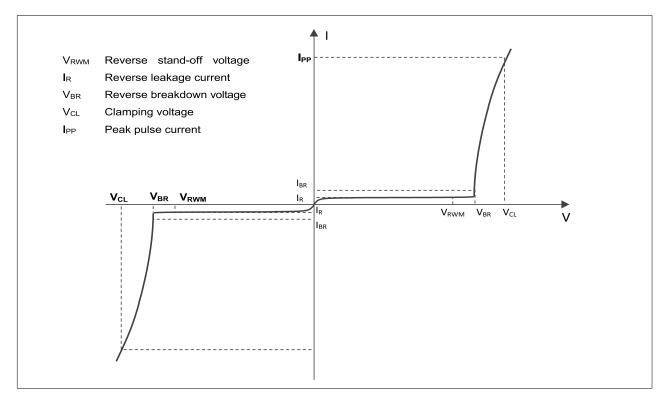
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	P <sub>PK</sub>	360	W
Peak Pulse Current (8/20µs)	l <sub>PP</sub>	6	Α
ESD per IEC 61000-4-2 (Air)			kV
ESD per IEC 61000-4-2 (Contact)	V <sub>ESD</sub>	±15	kV
Maximum lead temperature for soldering during 10s	TL	260	°C
Operating Temperature Range	T <sub>OP</sub>	−40 to +125	°C
Storage Temperature Range	T <sub>STG</sub>	−55 to +150	°C

## Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	$V_{RWM}$			24	V	
Reverse Breakdown Voltage	V <sub>BR</sub>	26.5		31	V	$I_T = 1mA$
Reverse Leakage Current	I <sub>R</sub>			100	nA	V <sub>RWM</sub> =24V
Clamping Voltage	Vc			36	V	I <sub>PP</sub> = 1A (8/20µs pulse)
Clamping Voltage	Vc			60	V	I <sub>PP</sub> = 6A (8/20µs pulse)
Junction Capacitance	Сл		15	20	pF	$V_R = 0V$ , $f = 1MHz$



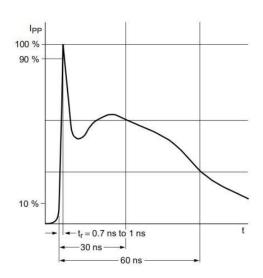
### Electrical characteristics (T<sub>A</sub> = 25 °C, unless otherwise noted)

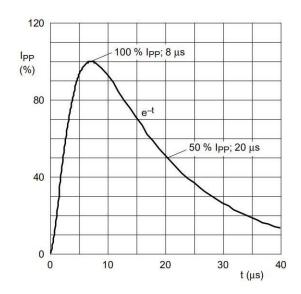


Definitions of electrical characteristics



# Typical Performance Characteristics (TA=25°C unless otherwise Specified



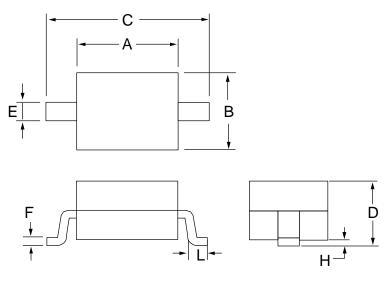


IEC61000-4-2 Waveform

IEC 61000-4-5 Waveform( 8/20µs pulse)

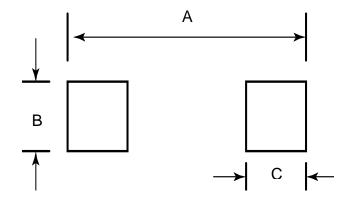


## **SOD-323 Package Outline Drawing**



SYM	DIMENSIONS					
	MILLIMETERS			INC	HES	
	MIN	NOM	MAX	MIN	MAX	
А	1.50	1.65	1.80	0.060	0.071	
В	1.20	1.30	1.40	0.045	0.054	
С	2.30	2.50	2.70	0.090	0.107	
D	-		1.10	-	0.043	
Е	0.30		0.40	0.012	0.016	
F	0.10		0.25	0.004	0.010	
L	0.20		0.40	0.008	0.016	
Н	-		0.10	-	0.004	

# **Suggested Land Pattern**

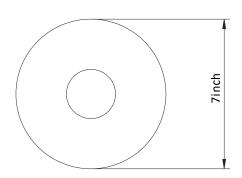


SYM	DIMENSIONS				
01111	MILLIMETERS	INCHES			
A	3.15	0.120			
В	0.80	0.031			
С	0.80	0.031			

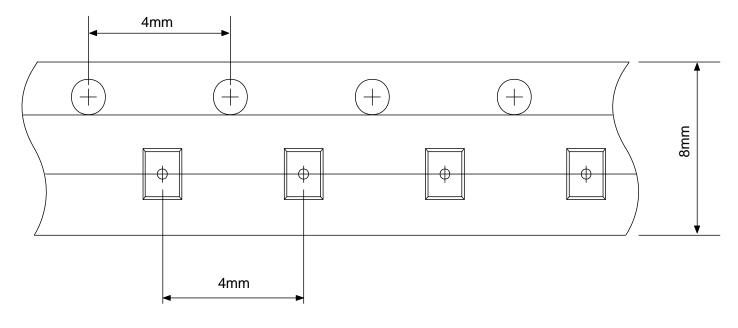


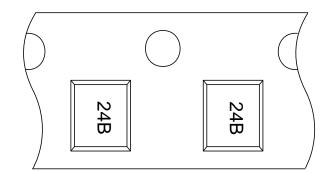
### **TAPE AND REEL INFORMATION**

#### **Reel Dimensions**



### **Tape Dimensions**









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